NSN 5961-01-109-4164

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View Online at https://aerobasegroup.com/nsn/5961-01-109-4164 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.188 inches **Overall Diameter:** 0.200 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-base, emitter open and 20.0 breakdown voltage, collector-to-emitter, base open and 3.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 0.20 amperes source cutoff current **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 uninsulated wire lead and 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

Yes - demil/mli